

MH232 Hall-effect sensor is a temperature stable, stress-resistant, Low Tolerance of Sensitivity Ultra-power switch. Superior high-temperature performance is made possible through a dynamic offset cancellation that utilizes chopper-stabilization. This method reduces the offset voltage normally caused by device over molding, temperature dependencies, and thermal stress.

MH232 is special made for low operation voltage, 2.7V, to active the chip which includes the following on a single silicon chip: voltage regulator, Hall voltage generator, small-signal amplifier, chopper stabilization, Schmitt trigger, CMOS output driver. Advanced CMOS wafer fabrication processing is used to take advantage of low-voltage requirements, component matching, very low input-offset errors, and small component geometries. This device can be operated on not only unipolar S or N, but omnipolar magnetic field.

The package type is in a Halogen Free version has been verified by third party Lab.

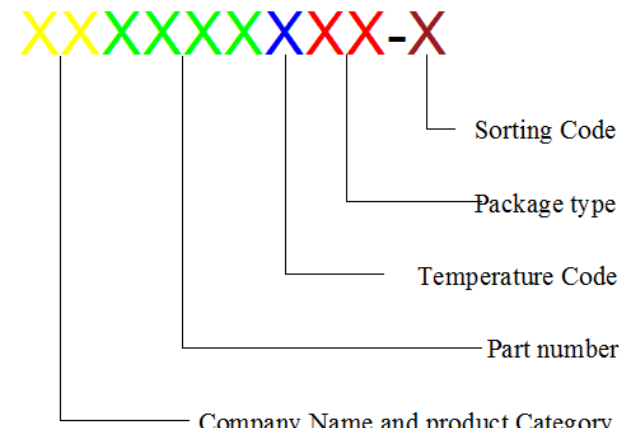
### ***Features and Benefits***

- CMOS Hall IC Technology
- Strong RF noise protection
- 2.7 to 5.5V for battery-powered applications
- Omni polar, output switches with absolute value of North or South pole from magnet
- Operation down to 2.7V, Micro power consumption
- High Sensitivity for reed switch replacement applications
- Low sensitivity drift in crossing of Temp. rang
- Multi Small Size option
- Ultra low power consumption at 1.6uA (Avg)
- High ESD Protection, HBM > ±4KV( min )
- Operation with South Pole (OUT1) or North Pole (OUT2)
- Totem-pole output
- RoHS compliant 2011/65/EU and Halogen Free

### ***Applications***

- Solid state switch
- Handheld wireless Handset Awake Switch(Flip Cell/PHS Phone/Note Book/Flip Video Set)
- Magnet proximity sensor for reed switch replacement in low duty cycle applications
- Water Meter
- PDA
- Tab PC
- Security
- Smart meter
- 3C
- TWS

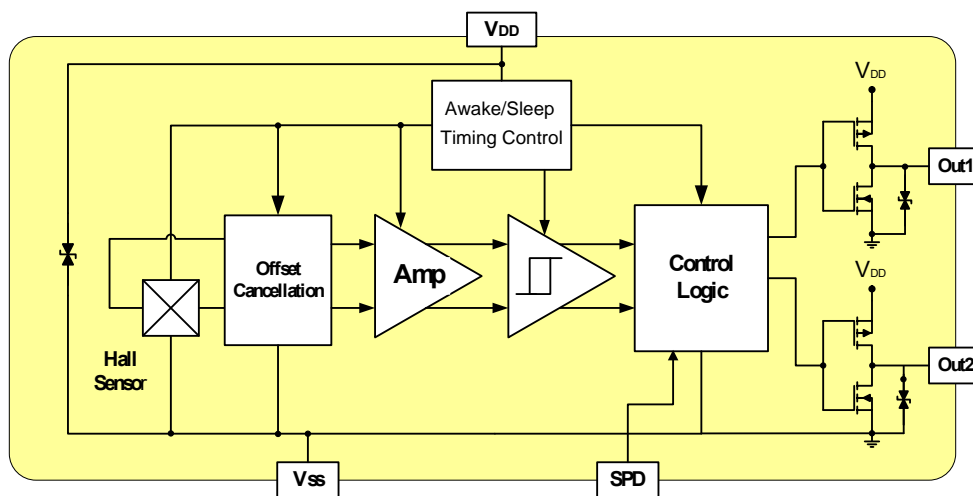
### Ordering Information

	<p><b>Company Name and Product Category</b> MH:MST Hall Effect/MP:MST Power MOSFET</p> <p><b>Part number</b> 181,182,183,184,185,248,249,276,477,381,381F,381R,382..... If part # is just 3 digits, the fourth digit will be omitted.</p> <p><b>Temperature range</b> E: 85 °C, I: 105 °C, K: 125 °C, L: 150 °C</p> <p><b>Package type</b> UA:TO-92S,VK:TO-92S(4pin),VF:TO-92S(5pin),SO:SOT-23, SQ:QFN-3,ST:TSOT-23,SN:SOT-553,SF:SOT-89(5pin)</p> <p><b>Sorting</b> α,β,Blank.....</p>
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Part No.	Temperature Suffix	Package Type
MH232NEUA	E (-40°C to + 85°C)	UA (TO-92S)
MH232SEUA	E (-40°C to + 85°C)	UA (TO-92S)
MH232NEST	E (-40°C to + 85°C)	ST (TSOT-23)
MH232SEST	E (-40°C to + 85°C)	ST (TSOT-23)
MH232ESD	E(-40°C to +85°C)	SD (DFN2*2-6L)
MH232ESS	E (-40°C to + 85°C)	SS (QFN1x1-4L)

Custom sensitivity selection is available by MST sorting technology

### Functional Diagram



**Note:** Static sensitive device; please observe ESD precautions. Reverse  $V_{DD}$  protection is not included. For reverse voltage protection, a 100Ω resistor in series with  $V_{DD}$  is recommended.

**MH232, HBM > ±4KV which is verified by third party lab.**

### Absolute Maximum Ratings At( $T_a=25^{\circ}\text{C}$ )

Characteristics		Values	Unit
Supply voltage, ( $V_{DD}$ )		6.0	V
Output Voltage, ( $V_{out}$ )		6.0	V
Magnetic flux density		Unlimited	Gauss
Output current, ( $I_{OUT}$ )		5	mA
Operating temperature range, ( $T_a$ )		-40 to +85	$^{\circ}\text{C}$
Storage temperature range, ( $T_s$ )		-65 to +150	$^{\circ}\text{C}$
Maximum Junction Temp, ( $T_j$ )		150	$^{\circ}\text{C}$
Thermal Resistance	( $\theta_{JA}$ ) UA/ST/SS/SD	206/543/300/160	$^{\circ}\text{C}/\text{A}$
	( $\theta_{JC}$ ) UA/ST/SS/SD	148/410/52/35	$^{\circ}\text{C}/\text{A}$
Package Power Dissipation, ( $P_D$ ) UA/ST/SS/SD		606/230/416/780	mW

**Note:** Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.

### Electrical Specifications

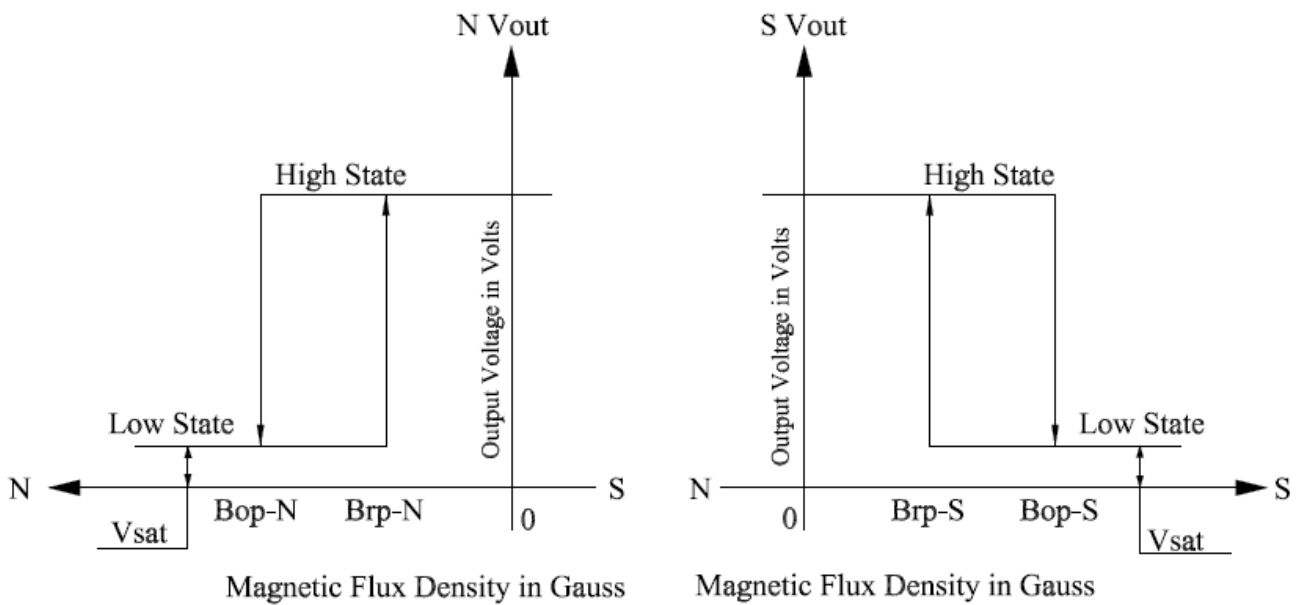
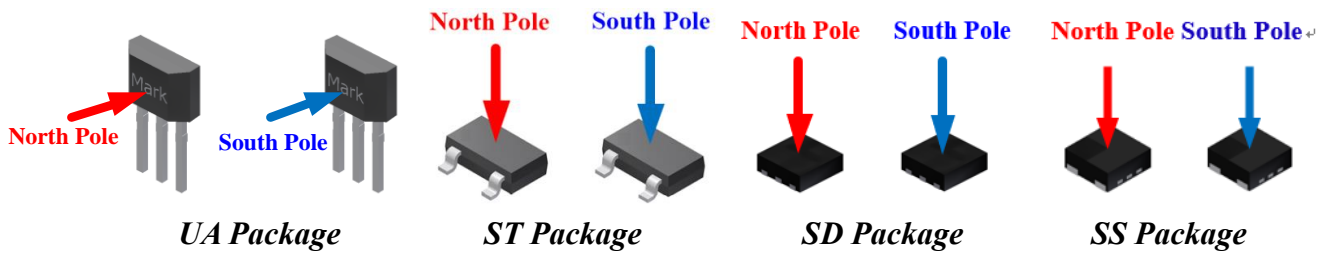
DC Operating Parameters :  $T_a=25^{\circ}\text{C}$ ,  $V_{DD}=3.0\text{V}$

Parameters	Test Conditions	Min	Typ	Max	Units
Supply Voltage, ( $V_{DD}$ )	Operating	2.7		5.5	V
Supply Current, ( $I_{DD}$ )	Awake State		2.0		mA
	Sleep State		1.0		$\mu\text{A}$
	Average (SPD=Hi)		1.6/(135)		$\mu\text{A}$
Output High Voltage, ( $V_{OH}$ )	$I_{OUT}=1.0\text{mA}$ (Source)	$V_{DD}-0.2$			V
Output Low Voltage, ( $V_{OL}$ )	$I_{OUT}=1.0\text{mA}$ (Sink)			0.2	V
Awake mode time, ( $T_{aw}$ )	Operating		20	40	$\mu\text{s}$
Sleep mode time, ( $T_{SL}$ )	Operating (SPD=Hi)		80/(0.16)	150(0.32)	mS
Duty Cycle, ( $D, C$ )	(SPD=Hi)		0.025/(12.5)		%
Power-On Time, ( $T_{PO}$ )			16	32	nS
Output Switch Time, ( $T_{SW}$ )	Operating (SPD=Hi)		80(0.2)	160(0.4)	mS
Output Switch Frequency, ( $F_{SW}$ )	Operating (SPD=Hi)	15/(6.5k)			Hz
Electro-Static Discharge	HBM	4			KV
Operate Point, $B_{OP\text{S}}$ (Output S)	$B > B_{OP\text{S}}$	20		55	Gauss
Release Point, $B_{RP\text{S}}$ (Output S)	$B < B_{RP\text{S}}$	10		45	Gauss
Operate Point, $B_{OP\text{N}}$ (Output N)	$B >  B_{OP\text{N}} $	-55		-20	Gauss
Release Point, $B_{RP\text{N}}$ (Output N)	$B <  B_{RP\text{N}} $	-45		-10	Gauss
Hysteresis, (BHYS)	$ B_{OP\text{X}} - B_{RP\text{X}} $		10		Gauss

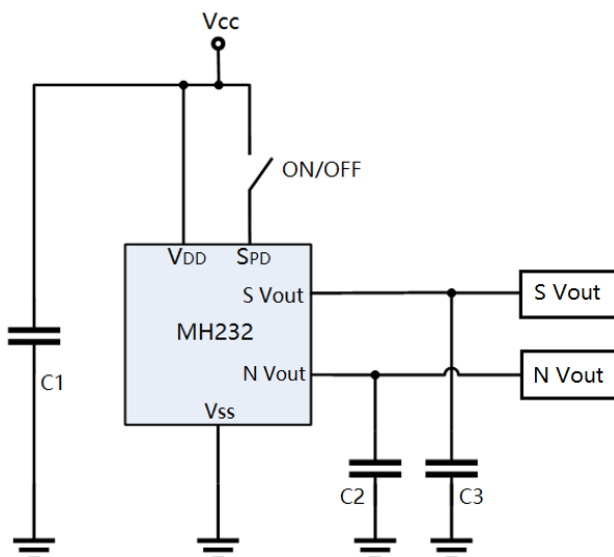
### MH232NEUA/SEUA/NEST/SEST/ESS/ESD Output Behavior versus Magnetic Polar

DC Operating Parameters:  $T_a = -40$  to  $85^\circ\text{C}$ ,  $V_{DD} = 2.7\text{V}$  to  $5.5\text{V}$

Parameter	Test condition	S vout	Test condition	N Vout
South pole	$B > B_{OPS}$	Low	--	High
Null or weak magnetic field	$B=0$ or $B < B_{RPS}$	High	$B=0$ or $B <  B_{RPN} $	High
North pole	--	High	$B >  B_{OPN} $	Low



### Typical application circuit

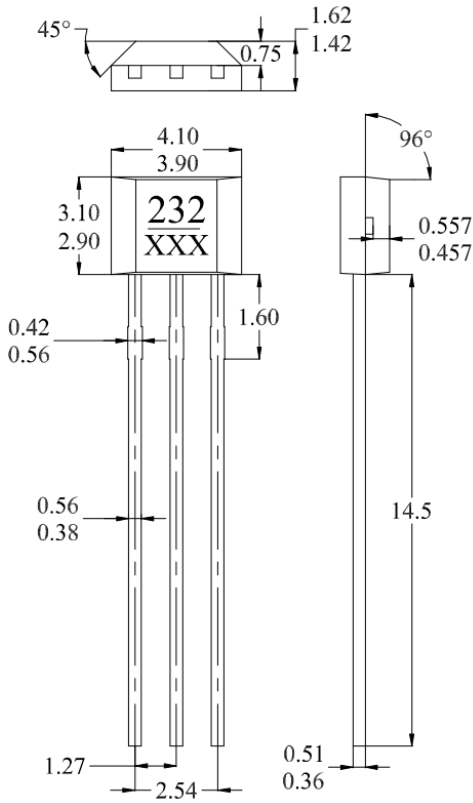


C1 : 10nF

C2 : 100pF

### Sensor Location, package dimension and marking

#### MH232SEUA Package

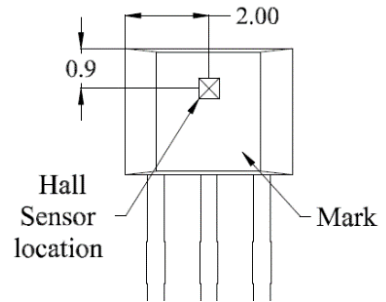


#### NOTES:

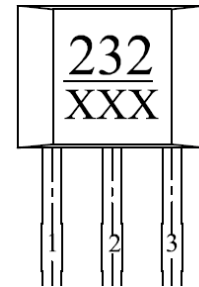
- Controlling dimension: mm
- Leads must be free of flash and plating voids
- Do not bend leads within 1 mm of lead to package interface.
- PINOUT:
 

Pin 1	VCC
Pin 2	GND
Pin 3	Output
- XXX; 1<sup>st</sup> X=Year; 2<sup>nd</sup> and 3<sup>rd</sup> XX=Week

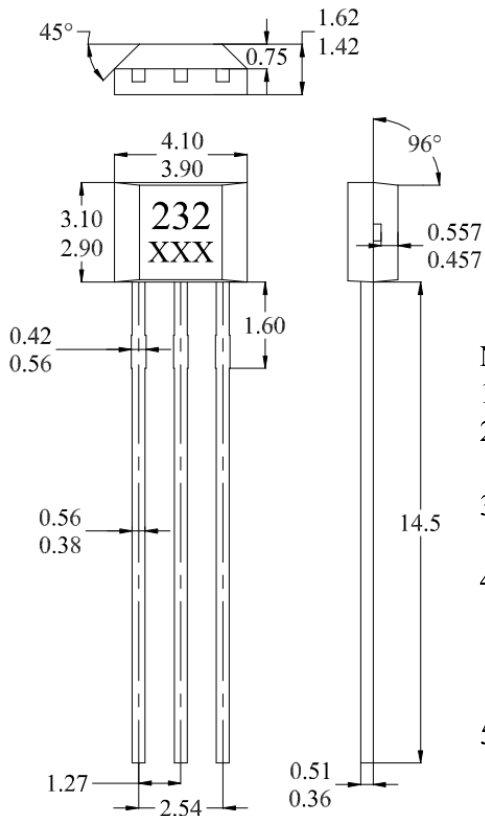
#### Hall Chip location



#### Output Pin Assignment (Top view)



#### MH232NEUA Package

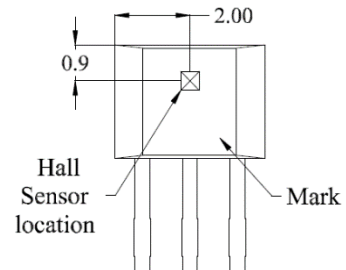


#### NOTES:

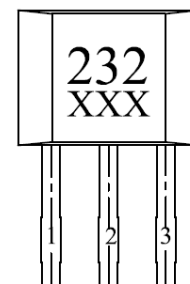
- Controlling dimension: mm
- Leads must be free of flash and plating voids
- Do not bend leads within 1 mm of lead to package interface.
- PINOUT:
 

Pin 1	VCC
Pin 2	GND
Pin 3	Output
- XXX; 1<sup>st</sup> X=Year; 2<sup>nd</sup> and 3<sup>rd</sup> XX=Week

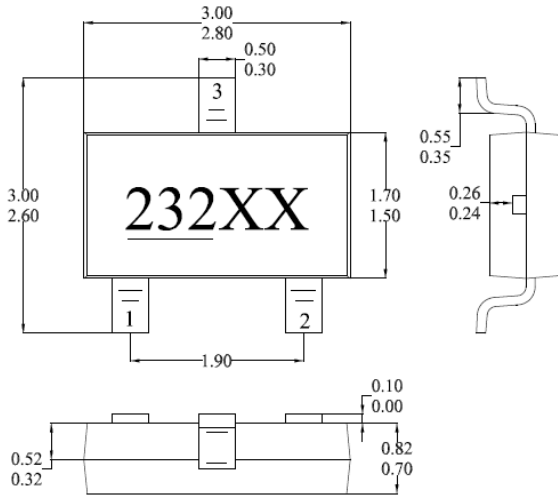
#### Hall Chip location



#### Output Pin Assignment (Top view)



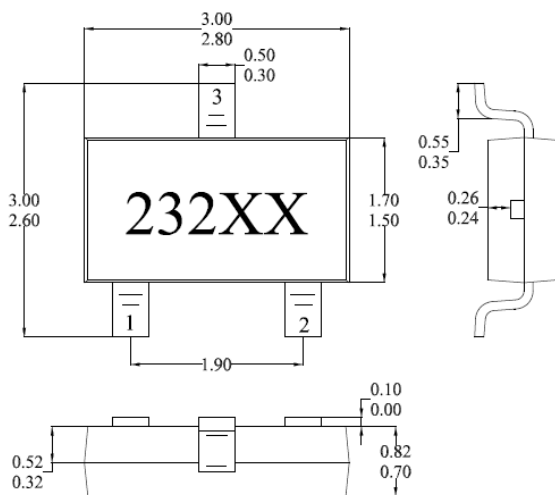
**MH232SEST Package**  
**(Top View)**



**NOTES:**

1. PINOUT (See Top View at left :)  
Pin 1  $V_{DD}$   
Pin 2 Output  
Pin 3 GND
2. Controlling dimension: mm
3. Lead thickness after solder plating will be 0.254mm maximum
4. XX: Date Code, Refer to DC table

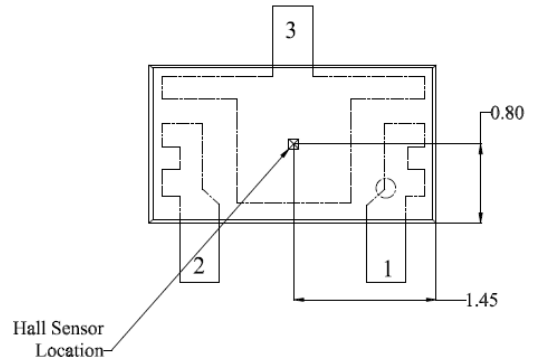
**MH232NEST Package**  
**(Top View)**



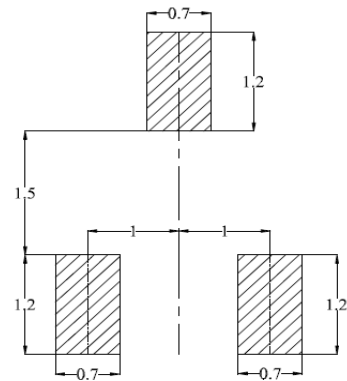
**NOTES:**

1. PINOUT (See Top View at left :)  
Pin 1  $V_{DD}$   
Pin 2 Output  
Pin 3 GND
2. Controlling dimension: mm
3. Lead thickness after solder plating will be 0.254mm maximum
4. XX: Date Code, Refer to DC table

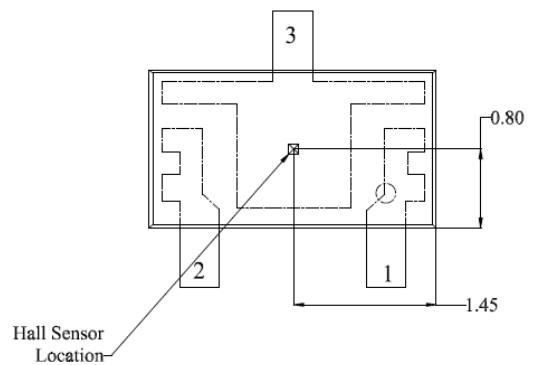
**Hall Plate Chip Location**  
**(Bottom view)**



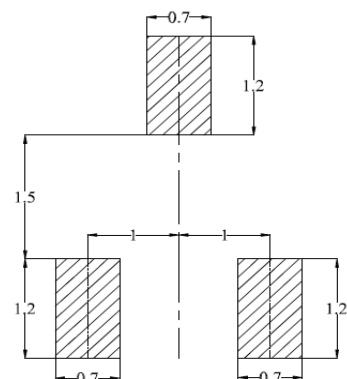
**(For reference only) Land Pattern**



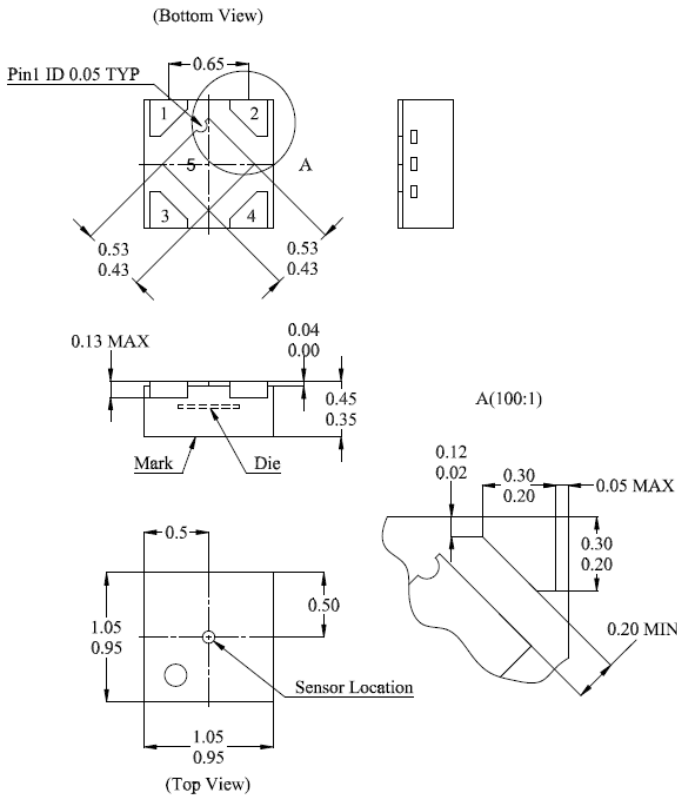
**Hall Plate Chip Location**  
**(Bottom view)**



**(For reference only) Land Pattern**



### SS Package (DFN1x1-4L)



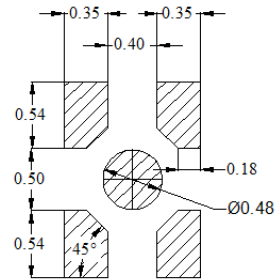
### NOTES:

Controlling dimension: mm

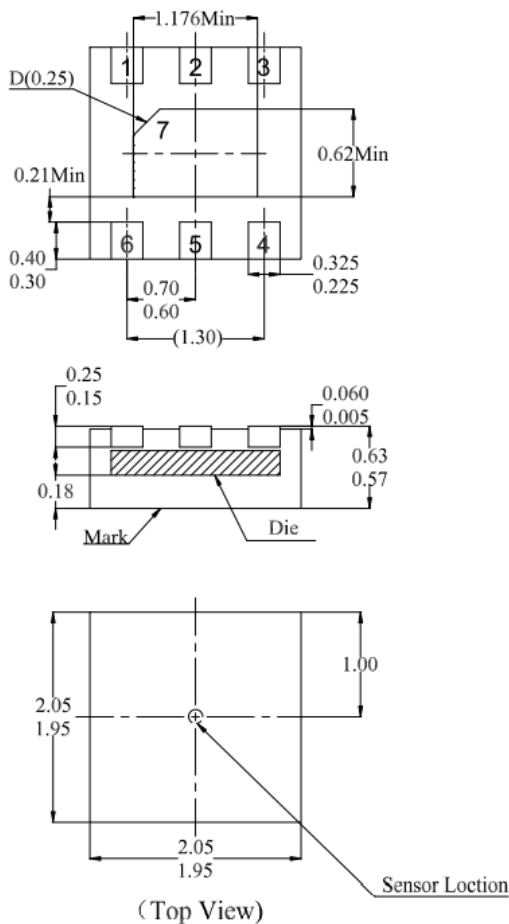
1. Leads must be free of flash and plating voids
2. Lead thickness after solder plating will be 0.254mm maximum
3. DC
4. PINOUT:

Pin No.	Pin Name	Function
1	V <sub>DD</sub>	Power Supply
2	V <sub>SS</sub>	Ground
3	S V <sub>OUT</sub>	Output1
4	N V <sub>OUT</sub>	Output2
5	PAD	NC

5. (For reference only) Land pattern



### SD package (DFN2x2-6L)



### NOTES:

Controlling dimension: mm

1. Leads must be free of flash and plating voids
2. Lead thickness after solder plating will be 0.254mm maximum
3. PINOUT:

Pin No.	Pin Name	Function
1	V <sub>DD</sub>	Power Supply
2	N V <sub>OUT</sub>	Output2
3	S V <sub>OUT</sub>	Output1
4	N.C	N.C
5	V <sub>SS</sub>	Ground
6	SPD	Set pin
7	PAD	Ground

4. (For reference only) Land pattern

